

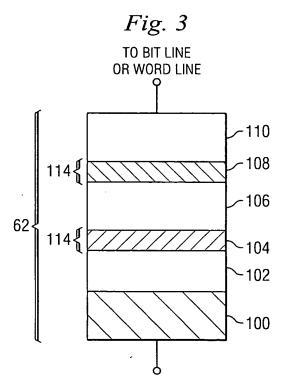
, , , ,

TO BIT LINE(S)
OR WORD LINE(S)
60

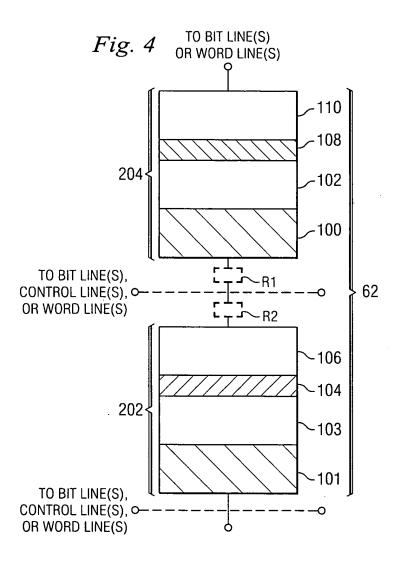
MTJ
CONFIGURATION

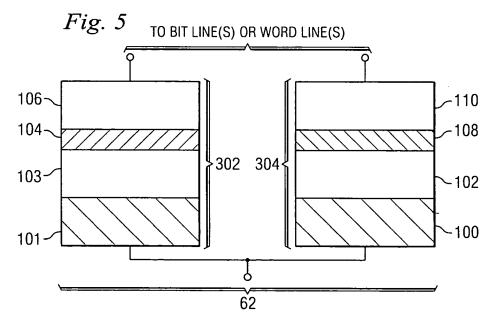
SWITCHING
DEVICE
68

TO WORD LINE
OR BIT LINE



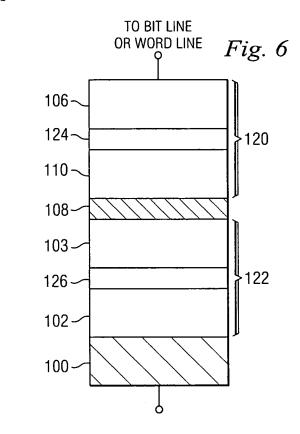
2/4

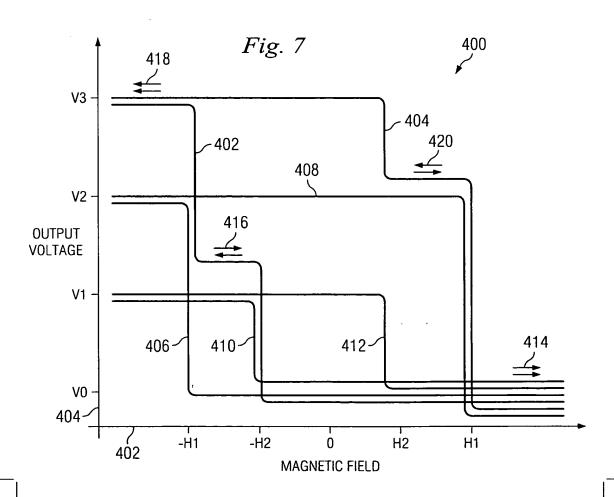




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WITH DIFFERENT MAGNETORESISTANCE
RATIOS

3/4





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